

UNISONIC TECHNOLOGIES CO., LTD

UT3N06 Power MOSFET

N-CHANNEL ENHANCEMENT MODE POWER MOSFET

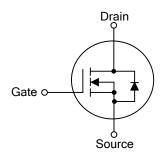
DESCRIPTION

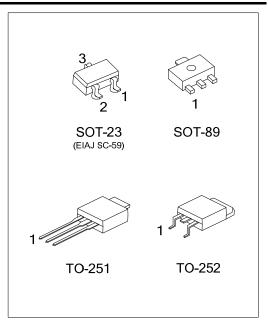
The UTC UT3N06 is an N-channel power MOSFET providing very low on-resistance. It has high efficiency and perfect cost-effectiveness. It can be generally applied in the commercial and industrial fields.

FEATURES

* Simple drive requirement

SYMBOL

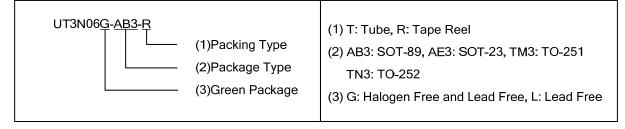




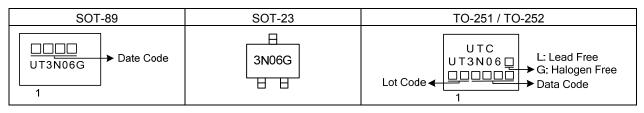
ORDERING INFORMATION

Ordering Number		Doolsono	Pin Assignment			Dealing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
-	UT3N06G-AB3-R	SOT-89	G	D	S	Tape Reel	
-	UT3N06G-AE3-R	SOT-23	S	G	D	Tape Reel	
UT3N06L-TM3-T	UT3N06G-TM3-T	TO-251	G	D	S	Tube	
UT3N06L-TN3-R	UT3N06G-TN3-R	TO-252	G	D	S	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



MARKING



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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL RATINGS		UNIT	
Drain-Source Voltage		$V_{ extsf{DSS}}$	60	V	
Gate-Source Voltage		V_{GSS}	±20	V	
Continuous Drain Current (V _{GS} =4.5V, T _A = 25°C) (Note 2)		I _D	3.0	Α	
Pulsed Drain Current (Note 3, 4)		I _{DM}	10	Α	
Power Dissipation (T _A = 25°C)	SOT-23		0.35	W	
	SOT-89	P_{D}	0.69	W	
	TO-251/TO-252		1.13	W	
Junction Temperature		T _J	+150	°C	
Storage Temperature		T _{STG}	-55 ~ +150	°C	

- Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
 - 2. Surface mounted on 1 in² copper pad of FR4 board; 270°C/W when mounted on min. copper pad
 - 3. Pulse width limited by $T_{J(MAX)}$
 - 4. Pulse width ≤300µs, duty cycle≤2%

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT
Junction to Ambient	SOT-23		350	°C/W
	SOT-89	θ_{JA}	180	°C/W
	TO-251/TO-252		110	°C/W

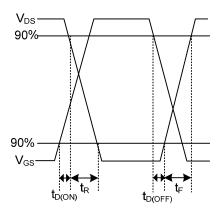
■ **ELECTRICAL CHARACTERISTICS** (T_J = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV _{DSS}	$V_{GS} = 0V, I_D = 250 \mu A$	60			V		
Breakdown Voltage Temperature Coefficient	$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Reference to 25°C, I _D =1mA		0.05		V/°C		
Drain-Source Leakage Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V			10	μΑ		
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V			±100	nA		
ON CHARACTERISTICS								
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	1.0		3.0	V		
Drain to Source On-state Resistance		V_{GS} =10V, I_D =3A			90	mΩ		
Drain to Source On-state Resistance	$R_{DS(ON)}$	$V_{GS} = 4.5V, I_D = 2A$			120	mΩ		
DYNAMIC PARAMETERS								
Input Capacitance	C _{ISS}			490	780	pF		
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V,f =1.0MHz		55		pF		
Reverse Transfer Capacitance	C _{RSS}			40		pF		
SWITCHING PARAMETERS						-		
Turn-ON Delay Time (Note)	t _{D(ON)}			6		ns		
Turn-ON Rise Time	t _R	V _{GS} =10V, V _{DS} =30V, I _D =1A,		5	42	ns		
Turn-OFF Delay Time	t _{D(OFF)}	$R_D = 30\Omega$, $R_G = 3.3\Omega$		16		ns		
Turn-OFF Fall-Time	t _F			3	58	ns		
Total Gate Charge (Note)	Q_G			6	10	nC		
Gate Source Charge	Q_{GS}	$V_{GS} = 4.5V, V_{DS} = 48V, I_{D} = 3A$		1.6		nC		
Gate Drain Charge	Q_{GD}			3		nC		
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS								
Drain-Source Diode Forward Voltage (Note)	V_{SD}	I _S =1.2A, V _{GS} =0V			1.2	V		
Reverse Recovery Time	t _{rr}	1 = 2 A \ / = 0\ / d\/dt=100 A / us		25		ns		
Reverse Recovery Charge	Q_{RR}	I_S =3A, V_{GS} =0V, dI/dt=100A/ μ s		26		nC		

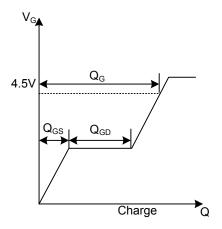
Note: Pulse width ≤300µs, duty cycle≤2%.



■ TEST WAVEFORMS



Switching Time Waveform

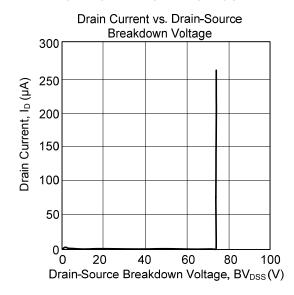


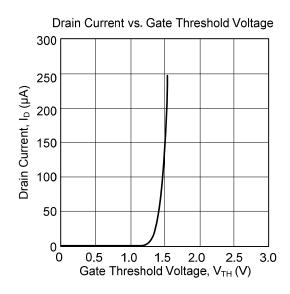
Gate Charge Waveform

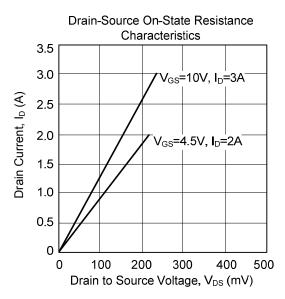
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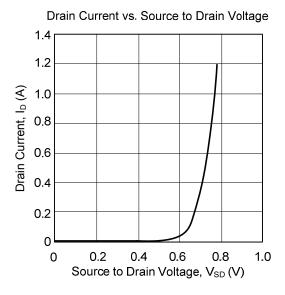
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TYPICAL CHARACTERISTICS









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